

# SKKT 72, SKKH 72, SKKT 72B



## SEMIPACK<sup>®</sup> 1

### Thyristor / Diode Modules

**SKKT 72**  
**SKKH 72**  
**SKKT 72B**

#### Features

- Heat transfer through aluminium oxide ceramic isolated metal baseplate
- Hard soldered joints for high reliability
- UL recognized, file no. E 63 532

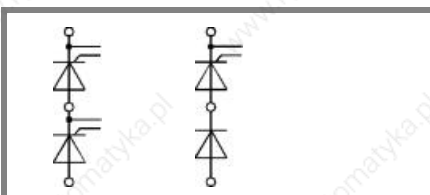
#### Typical Applications

- DC motor control (e. g. for machine tools)
- AC motor soft starters
- Temperature control (e. g. for ovens, chemical processes)
- Professional light dimming (studios, theaters)

1) See the assembly instructions

$V_{RSM}$ V	$V_{RRM}, V_{DRM}$ V	$I_{TRMS} = 125$ A (maximum value for continuous operation)		
		$I_{TAV} = 70$ A (sin. 180; $T_c = 85$ °C)		
900	800	SKKT 72/08E	SKKT 72B08E	SKKH 72/08E
1300	1200	SKKT 72/12E	SKKT 72B12E	SKKH 72/12E
1500	1400	SKKT 72/14E	SKKT 72B14E	SKKH 72/14E
1700	1600	SKKT 72/16E	SKKT 72B16E	SKKH 72/16E
1900	1800	SKKT 72/18E	SKKT 72B18E	SKKH 72/18E
2100	2000	SKKT 72/20EH4		SKKH 72/20EH4
2300	2200	SKKT 72/22EH4		SKKH 72/22EH4

Symbol	Conditions	Values	Units
$I_{TAV}$	sin. 180; $T_c = 85$ (100) °C	70 (50)	A
$I_D$	P3/180; $T_a = 45$ °C; B2 / B6	62 / 75	A
	P3/180F; $T_a = 35$ °C; B2 / B6	115 / 145	A
$I_{RMS}$	P3/180F; $T_a = 35$ °C; W1 / W3	155 / 3 * 115	A
$I_{TSM}$	$T_{vj} = 25$ °C; 10 ms	1600	A
	$T_{vj} = 125$ °C; 10 ms	1450	A
$i^2t$	$T_{vj} = 25$ °C; 8,3 ... 10 ms	13000	A <sup>2</sup> s
	$T_{vj} = 125$ °C; 8,3 ... 10 ms	10500	A <sup>2</sup> s
$V_T$	$T_{vj} = 25$ °C; $I_T = 300$ A	max. 1,9	V
$V_{T(TO)}$	$T_{vj} = 125$ °C	0,9	V
$r_T$	$T_{vj} = 125$ °C	3,5	mΩ
$I_{DD}; I_{RD}$	$T_{vj} = 125$ °C; $V_{RD} = V_{RRM}; V_{DD} = V_{DRM}$	max. 20	mA
$I_{DD}; I_{RD}$	for SKK .../20E; SKK .../22E	max. 30	mA
$t_{gd}$	$T_{vj} = 25$ °C; $I_G = 1$ A; $di_G/dt = 1$ A/μs	1	μs
$t_{gr}$	$V_D = 0,67 * V_{DRM}$	1	μs
$(di/dt)_{cr}$	$T_{vj} = 125$ °C	max. 150	A/μs
$(dv/dt)_{cr}$	$T_{vj} = 125$ °C	max. 1000	V/μs
$t_q$	$T_{vj} = 125$ °C	80	μs
$I_H$	$T_{vj} = 25$ °C; typ. / max.	150 / 250	mA
$I_L$	$T_{vj} = 25$ °C; $R_G = 33$ Ω; typ. / max.	300 / 600	mA
$V_{GT}$	$T_{vj} = 25$ °C; d.c.	min. 3	V
$I_{GT}$	$T_{vj} = 25$ °C; d.c.	min. 150	mA
$V_{GD}$	$T_{vj} = 125$ °C; d.c.	max. 0,25	V
$I_{GD}$	$T_{vj} = 125$ °C; d.c.	max. 6	mA
$R_{th(j-c)}$	cont.; per thyristor / per module	0,35 / 0,18	K/W
$R_{th(j-c)}$	sin. 180; per thyristor / per module	0,37 / 0,19	K/W
$R_{th(j-c)}$	rec. 120; per thyristor / per module	0,39 / 0,2	K/W
$R_{th(c-s)}$	per thyristor / per module	0,2 / 0,1	K/W
$T_{vj}$		- 40 ... + 125	°C
$T_{stg}$		- 40 ... + 125	°C
$V_{isol}$	a. c. 50 Hz; r.m.s.; 1 s / 1 min.	3600 / 3000	V~
$V_{isol}$	a. c. 50 Hz; r.m.s.; 1 s / 1 min. for SKK...H4	4800 / 4000	V~
$M_s$	to heatsink	5 ± 15 % <sup>1)</sup>	Nm
$M_t$	to terminals	3 ± 15 %	Nm
$a$		5 * 9,81	m/s <sup>2</sup>
$m$	approx.	95	g
Case	SKKT	A 46	
	SKKT ...B	A 48	
	SKKH	A 47	



**SKKT**      **SKKH**

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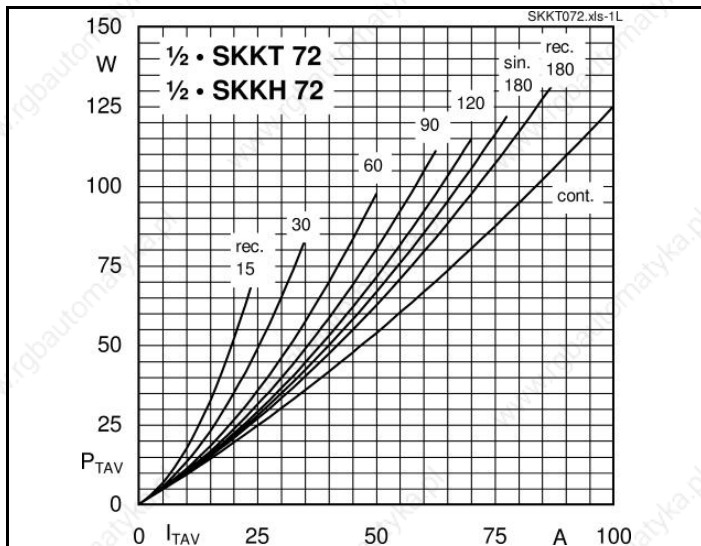


Fig. 1L Power dissipation per thyristor vs. on-state current

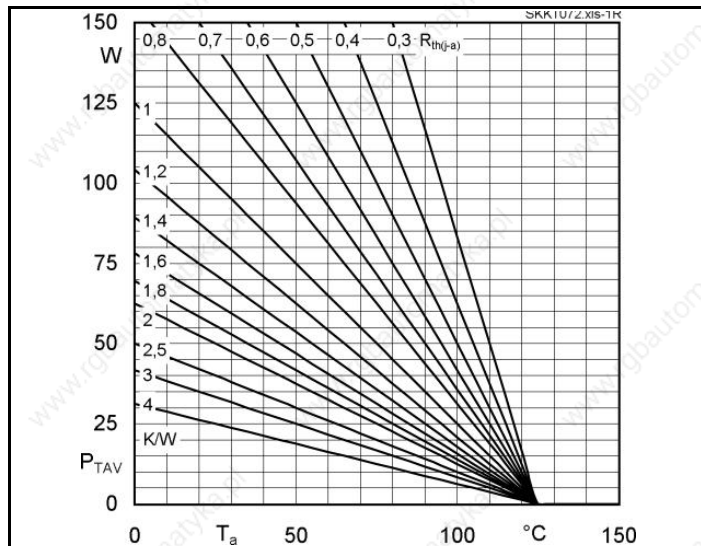


Fig. 1R Power dissipation per thyristor vs. ambient temp.

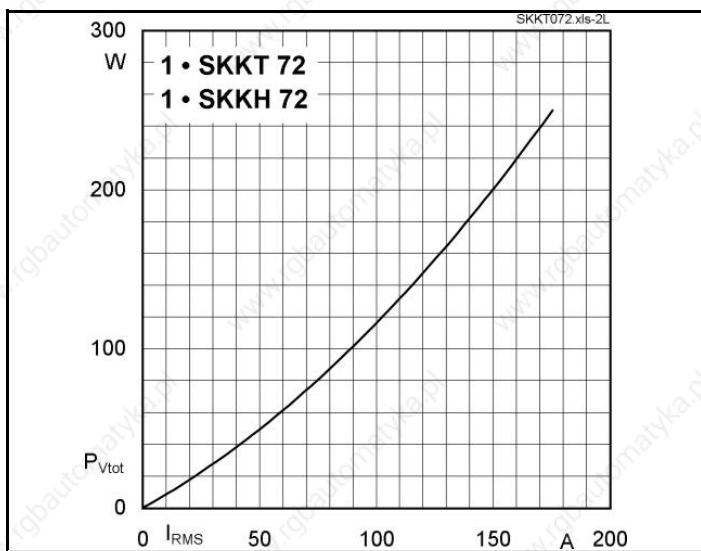


Fig. 2L Power dissipation per module vs. rms current

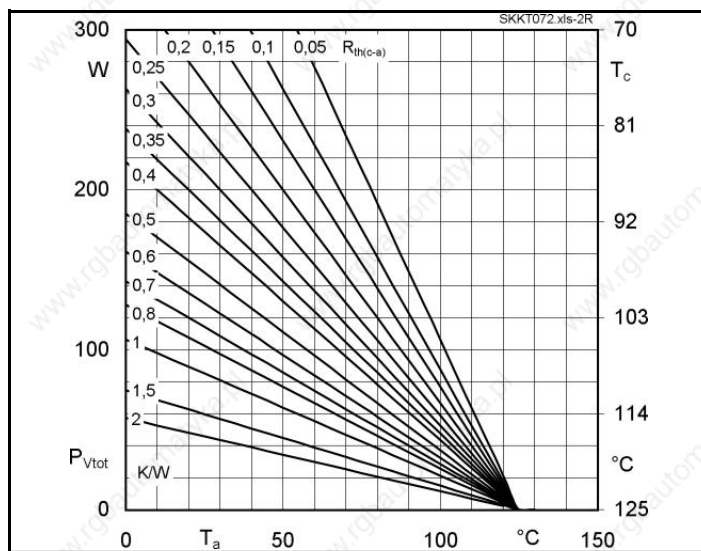


Fig. 2R Power dissipation per module vs. case temp.

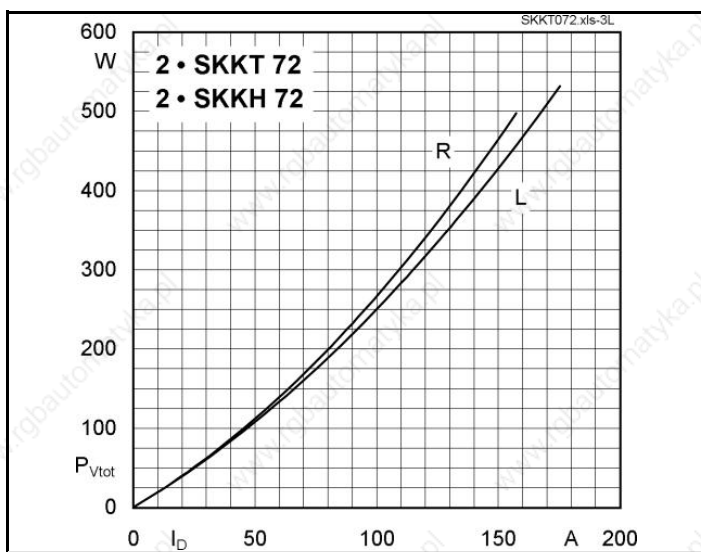


Fig. 3L Power dissipation of two modules vs. direct current

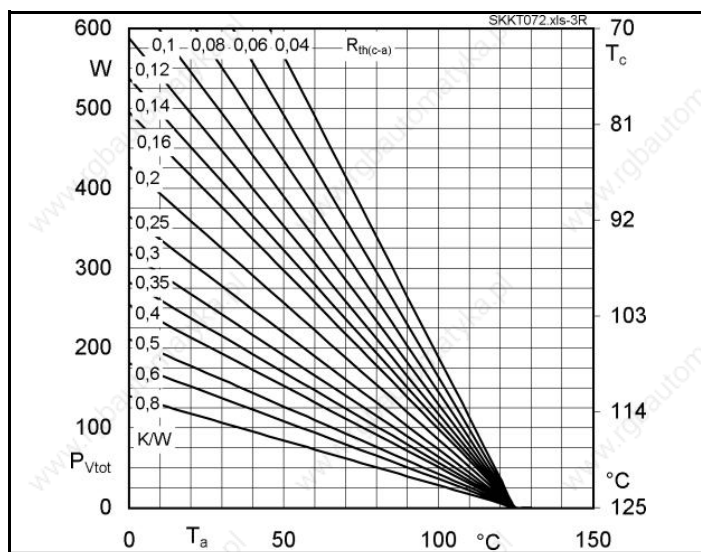
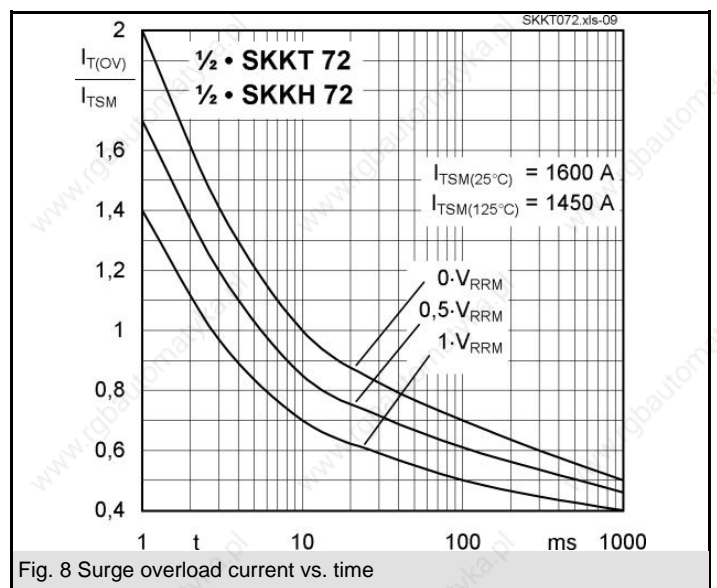
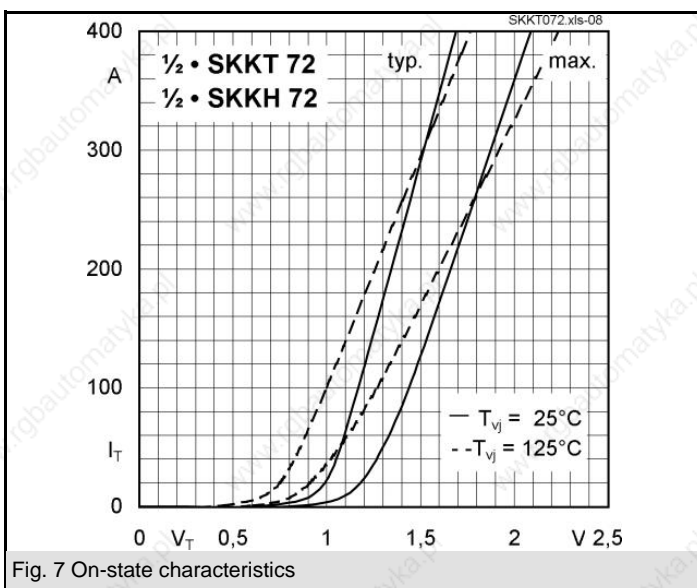
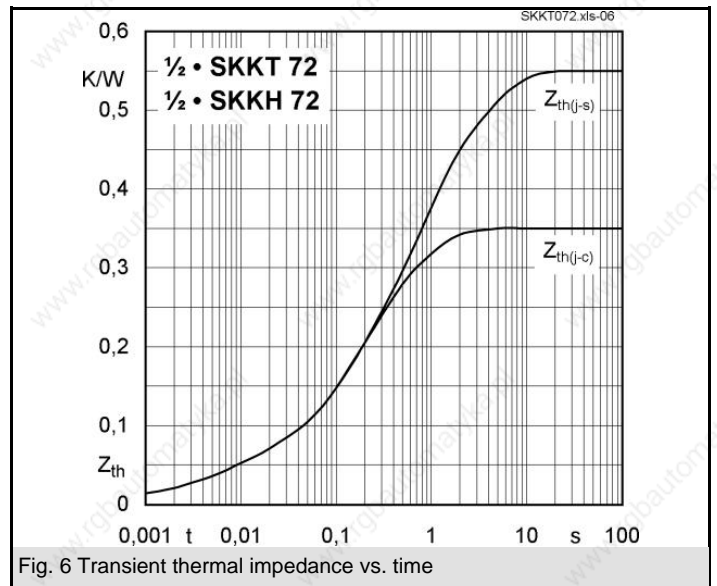
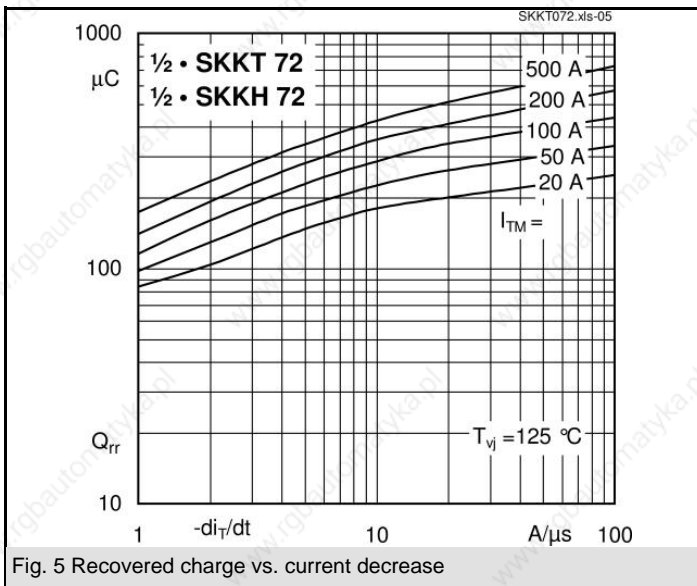
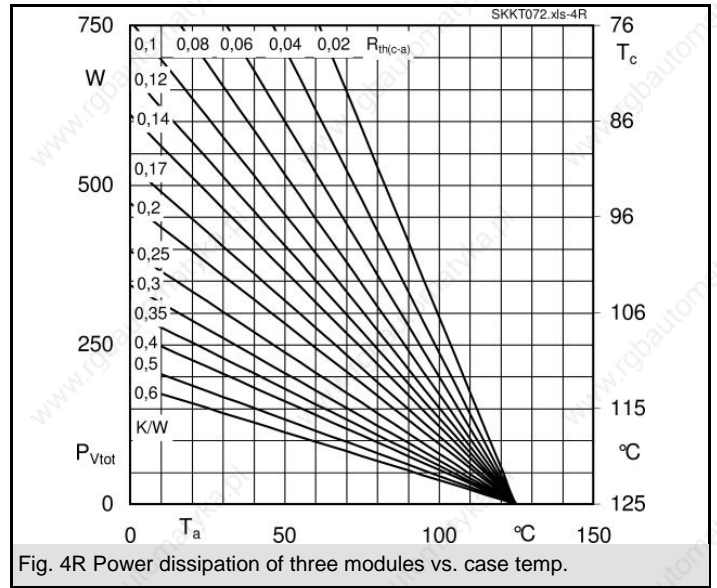
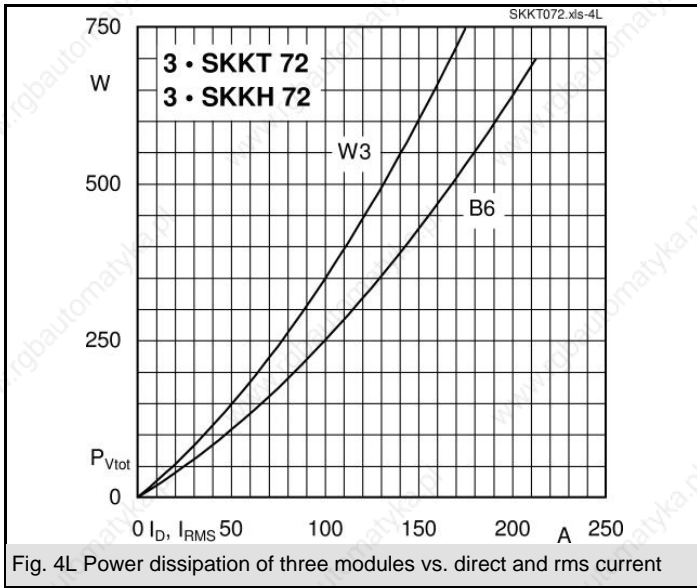
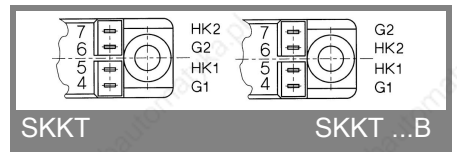
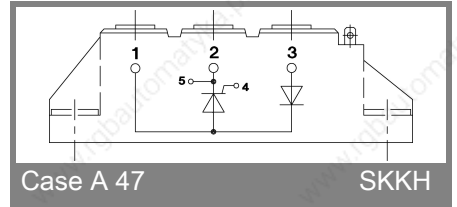
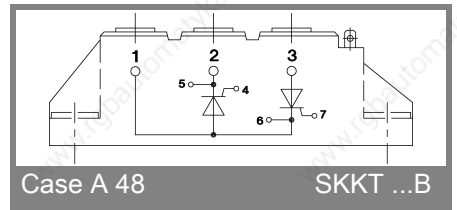
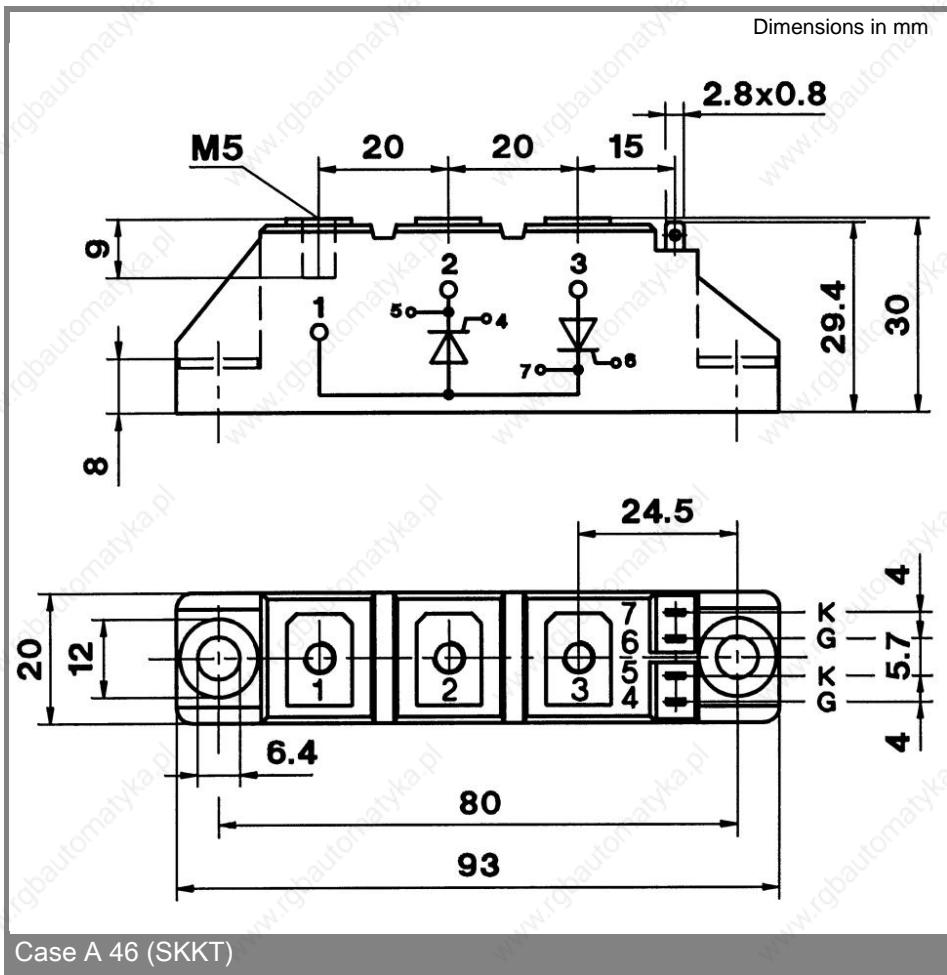


Fig. 3R Power dissipation of two modules vs. case temp.

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